High hfe Low VCE (sat)

2SC4024

Silicon NPN Epitaxial Planar Transistor

Application: DC-DC Converter, Emergency Lighting Inverter and General Purpose

Absolute maximum ratings (1a=25°C)							
Symbol	symbol 2SC4024						
Vсво	100	V					
VCEO	50	V					
VEBO	15	V					
Ic.	10	Λ					

35(Tc=25°C)

150

-55 to +150

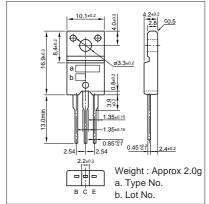
IB Pc

Τj

Tstg

Electrical C	naracteristics	(1a=25°C)		
Symbol	Conditions	2SC4024	Unit	
Ісво	Vcb=100V	10max	μΑ	
lebo	VEB=15V	V _{EB} =15V 10max		
V(BR)CEO	Ic=25mA	Ic=25mA 50min		
hfe	Vce=4V, Ic=1A	300 to 1600		
Vce(sat)	Ic=5A, IB=0.1A	Ic=5A, IB=0.1A 0.5max		
fT	Vce=12V, Ie=-0.5A	VCE=12V, IE=-0.5A 24typ		
Сов	Vcb=10V, f=1MHz	150typ	pF	

External Dimensions FM20(TO220F)



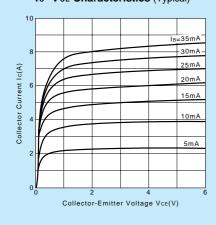
■Typical Switching Characteristics (Common Emitter)

W

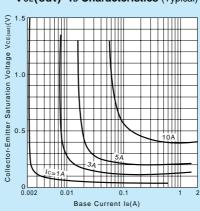
		•		•			
Vcc (V)	R _L (Ω)	Ic (A)	I _{B1} (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
20	4	5	0.1	-0.1	0.5typ	2.0typ	0.5typ

- Clastriani Characteristics

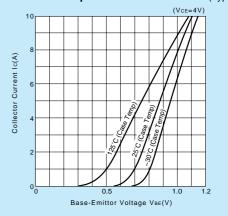
Ic-VcE Characteristics (Typical)



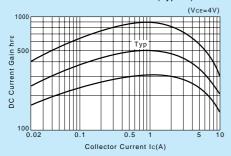
VcE(sat)-IB Characteristics (Typical)



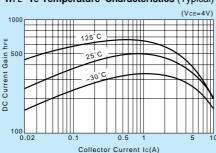
Ic-VBE Temperature Characteristics (Typical)



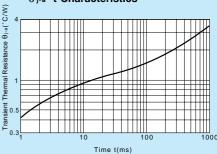
hfe-Ic Characteristics (Typical)



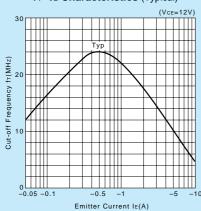
hfe-Ic Temperature Characteristics (Typical)



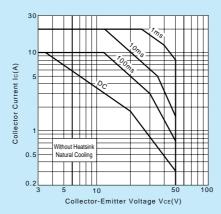
 $\theta_{\text{j-a}}$ -t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

